

SANYO Semiconductors DATA SHEET

P-Channel Silicon MOSFET

MCH3377 — General-Purpose Switching Device **Applications**

Features

- · Ultrahigh-speed switching.
- · 1.8V drive

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		-3	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-12	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² ×0.8mm)	1	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linis
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-20V, V _{GS} =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-1mA	-0.4		-1.3	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-1.5A	2.2	3.8		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =-1.5A, V _G S=-4.5V		63	83	mΩ
	R _{DS} (on)2	I _D =-1A, V _G S=-2.5V		88	125	mΩ
	RDS(on)3	In=-0.2A, Vgs=-1.8V		130	200	mΩ

Marking: QJ Continued on next page.

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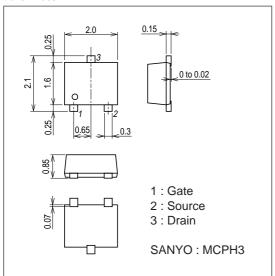
MCH3377

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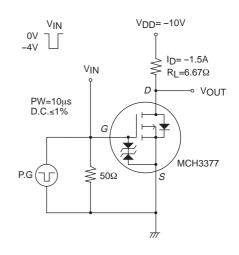
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		375		pF
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		77		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-10V, f=1MHz		58		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		8.1		ns
Rise Time	t _r	See specified Test Circuit.		26		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		42		ns
Fall Time	tf	See specified Test Circuit.		37		ns
Total Gate Charge	Qg	V _{DS} =-10V, V _{GS} =-4.5V, I _D =-3A		4.6		nC
Gate-to-Source Charge	Qgs	V _{DS} =-10V, V _{GS} =-4.5V, I _D =-3A		0.8		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-10V, V _{GS} =-4.5V, I _D =-3A		1.3		nC
Diode Forward Voltage	V _{SD}	IS=-3A, VGS=0V		-0.83	-1.2	V

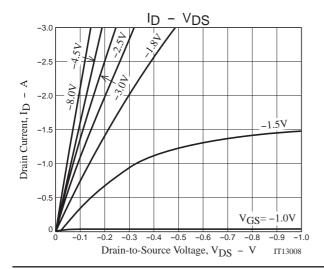
Package Dimensions

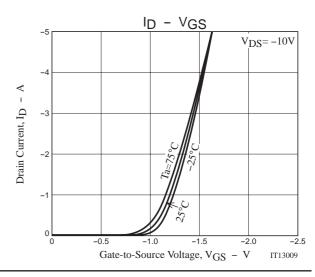
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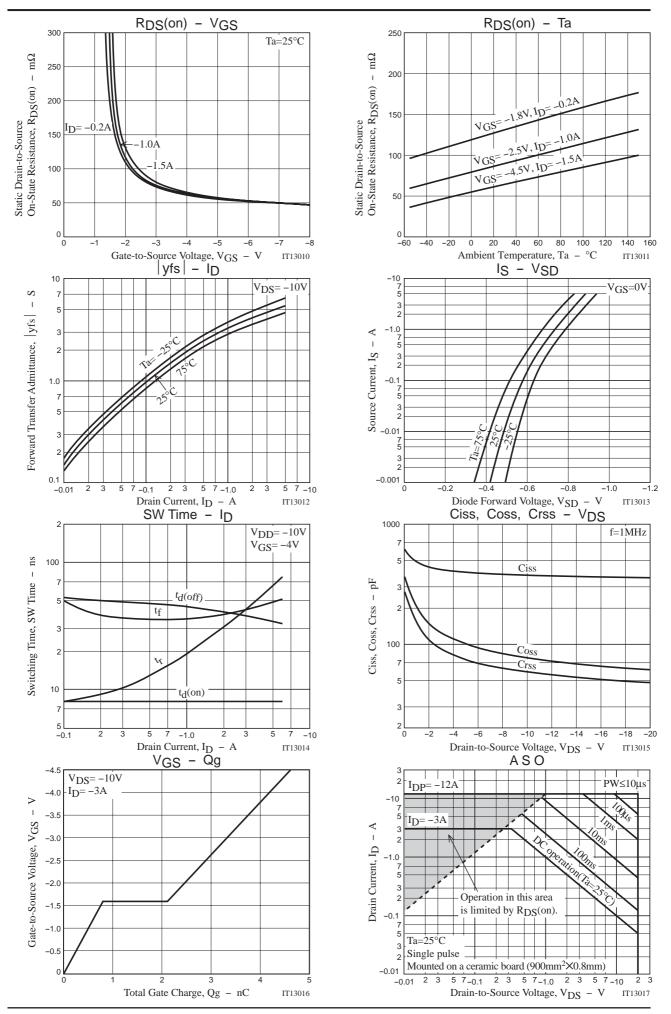


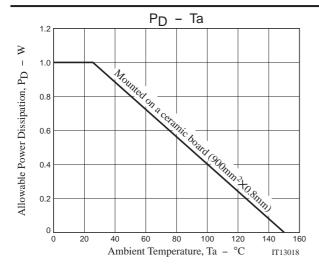
Switching Time Test Circuit











Note on usage: Since the MCH3377 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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